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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK1775

Silicon N Channel MOS FET

REJ03G0973-0200

(Previous: ADE-208-1320)

Rev.2.00 Sep 07, 2005

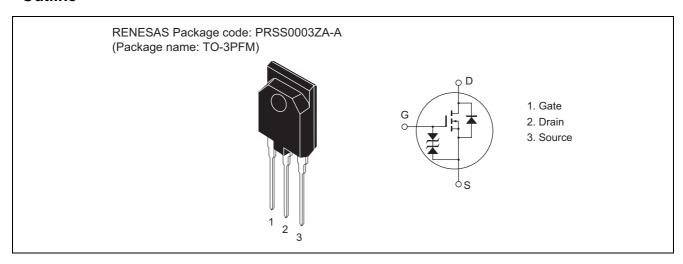
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator, DC-DC converter

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Ratings | Unit | |
|---|--------------------------|-------------|------|--|
| Drain to source voltage | V _{DSS} | 900 | V | |
| Gate to source voltage | V _{GSS} | ±30 | V | |
| Drain current | I _D | 8 | Α | |
| Drain peak current | I _{D(pulse)} *1 | 20 | Α | |
| Body to drain diode reverse drain current | I _{DR} | 8 | Α | |
| Channel dissipation | Pch ^{*2} | 60 | W | |
| Channel temperature | Tch | 150 | °C | |
| Storage temperature | Tstg | -55 to +150 | °C | |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

2. Value at Tc = 25°C

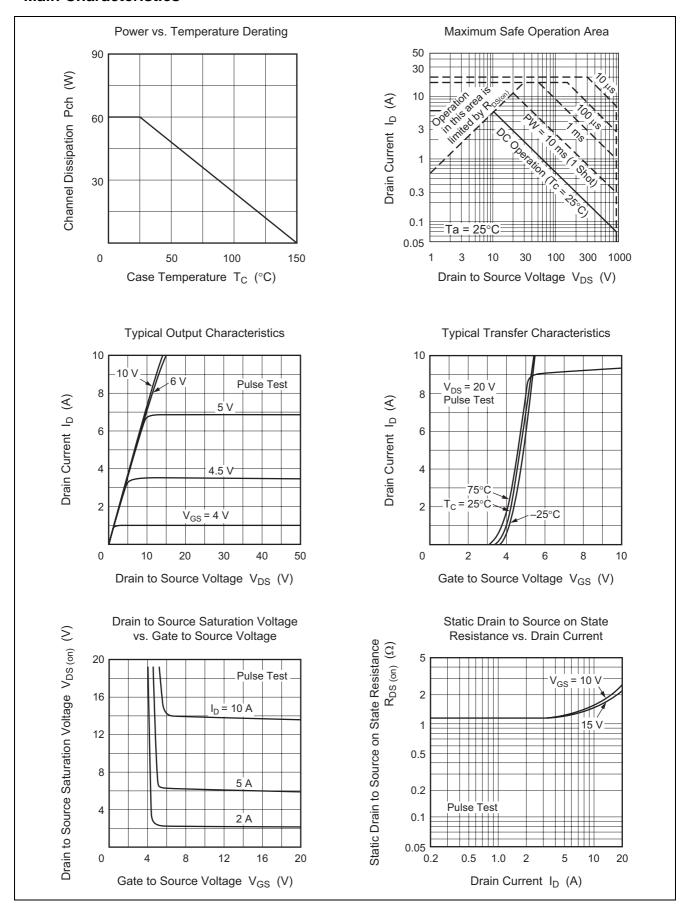
Electrical Characteristics

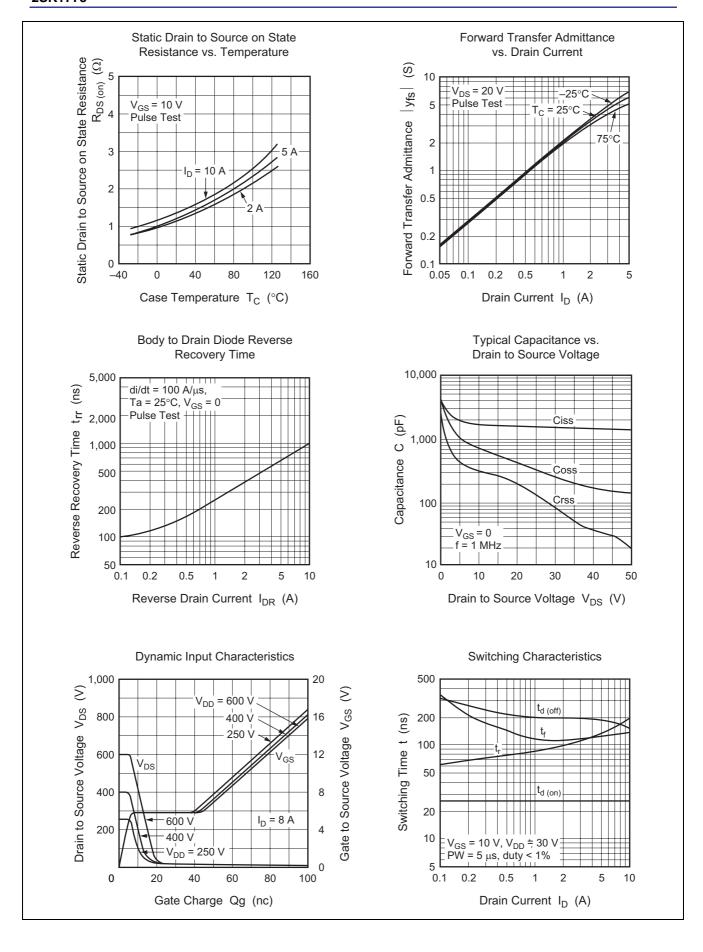
 $(Ta = 25^{\circ}C)$

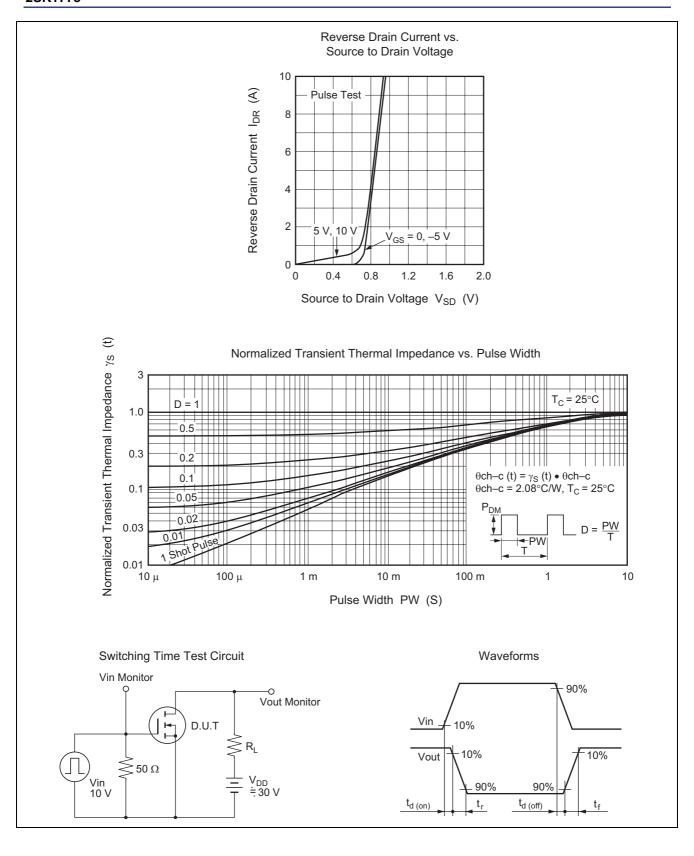
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|-------------------------------------|----------------------|-----|------|-----|------|---|
| Drain to source breakdown voltage | V _{(BR)DSS} | 900 | _ | _ | V | $I_D = 10 \text{ mA}, V_{GS} = 0$ |
| Gate to source breakdown voltage | V _{(BR)GSS} | ±30 | _ | _ | V | $I_G = \pm 100 \ \mu A, \ V_{DS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | 250 | μΑ | V _{DS} = 720 V, V _{GS} = 0 |
| Gate to source cutoff voltage | $V_{GS(off)}$ | 2.0 | _ | 3.0 | V | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$ |
| Static drain to source on state | R _{DS(on)} | _ | 1.2 | 1.6 | Ω | $I_D = 4 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$ |
| resistance | | | | | | |
| Forward transfer admittance | y _{fs} | 3.5 | 5.5 | _ | S | $I_D = 4 \text{ A}, V_{DS} = 20 \text{ V}^{*3}$ |
| Input capacitance | Ciss | _ | 1730 | | pF | $V_{DS} = 10 \text{ V}, V_{GS} = 0,$ |
| Output capacitance | Coss | _ | 700 | _ | pF | f = 1 MHz |
| Reverse transfer capacitance | Crss | _ | 310 | _ | pF | |
| Turn-on delay time | t _{d(on)} | _ | 25 | _ | ns | $I_D = 4 \text{ A}, V_{GS} = 10 \text{ V},$ |
| Rise time | t _r | _ | 135 | _ | ns | $R_L = 7.5 \Omega$ |
| Turn-off delay time | t _{d(off)} | _ | 185 | _ | ns | |
| Fall time | t _f | _ | 130 | _ | ns | |
| Body to drain diode forward voltage | V_{DF} | _ | 0.9 | _ | V | I _F = 8 A, V _{GS} = 0 |
| Body to drain diode reverse | t _{rr} | _ | 900 | _ | ns | $I_F = 8 A, V_{GS} = 0,$ |
| recovery time | | | | | | $di_F/dt = 100 A/\mu s$ |

Note: 3. Pulse Test

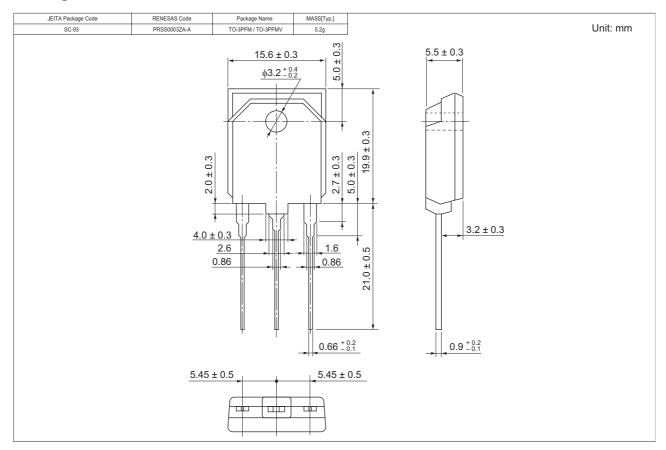
Main Characteristics







Package Dimensions



Ordering Information

| Part Name | Quantity | Shipping Container |
|-----------|----------|--------------------|
| 2SK1775-E | 360 pcs | Box (Tube) |

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